

## **Features**

Medium Power Complementary Silicon Transistors

# 1.BASE 2.COLLECTOR 3.EMITTER 1 TO-252-2L

## **Package Marking and Ordering Information**

Product ID	Pack	Packing Method	Qty(PCS)	
MJD41C	TO-252-2L	Tape and Reel	2500	

# Maximum Ratings (Ta=25°C unless otherwise noted)

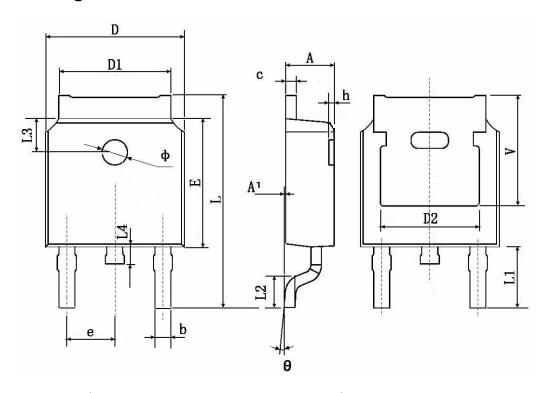
Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-Base Voltage	100	V
V <sub>CEO</sub>	Collector-Emitter Voltage	100	V
V <sub>EBO</sub>	Emitter-Base Voltage	6	V
Ic	Collector Current -Continuous	3	Α
Pc	Collector Power Dissipation	1	W
$T_J$ , $T_{stg}$	Operation Junction and Storage Temperature Range	-55~+150	℃

# B ...

## Electrical Characteristics (Ta=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Max	Unit
Collector-base breakdown voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> = 1mA, I <sub>E</sub> =0	100		V
Collector-emitter breakdown voltage	V <sub>CEO(sus)</sub>	I <sub>C</sub> = 1mA, I <sub>B</sub> =0	100		V
Emitter-base breakdown voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> = 1mA, I <sub>C</sub> =0	6		V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> =100V, I <sub>E</sub> =0		0.1	uA
Collector cut-off current	I <sub>CEO</sub>	V <sub>CE</sub> = 100V, I <sub>B</sub> = 0		0.5	uA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> =6V, I <sub>C</sub> =0		0.1	uA
DC surrent sein	h <sub>FE(1)</sub>	V <sub>CE</sub> =4V, I <sub>C</sub> = 1A	100	200	
DC current gain	h <sub>FE(2)</sub>	V <sub>CE</sub> =4V , I <sub>C</sub> = 3A	25		
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =1.5 A, I <sub>B</sub> =0.15A		0.5	
Transition frequency	f⊤	V <sub>CE</sub> =10V , I <sub>C</sub> =0.5A f =1MHz	50		$MH_Z$

## **TO-252-2L Package Outline Dimensions**



Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min.	Max.	Min.	Max.	
А	2.200	2.400	0.087	0.094	
A1	0.000	0.127	0.000	0.005	
b	0.660	0.860	0.026	0.034	
С	0.460	0.580	0.018	0.023	
D	6.500	6.700	0.256	0.264	
D1	5.100	5.460	0.201	0.215	
D2	0.483 TYP.		0.190 TYP.		
Е	6.000	6.200	0.236	0.244	
е	2.186	2.386	0.086	0.094	
L	9.800	10.400	0.386	0.409	
L1	2.900 TYP.		0.114 TYP.		
L2	1.400	1.700	0.055	0.067	
L3	1.600 TYP.		0.063 TYP.		
L4	0.600	1.000	0.024	0.039	
Ф	1.100	1.300	0.043	0.051	
θ	0°	8°	0°	8°	
h	0.000	0.300	0.000	0.012	
V	5.350 TYP.		0.211 TYP.		



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